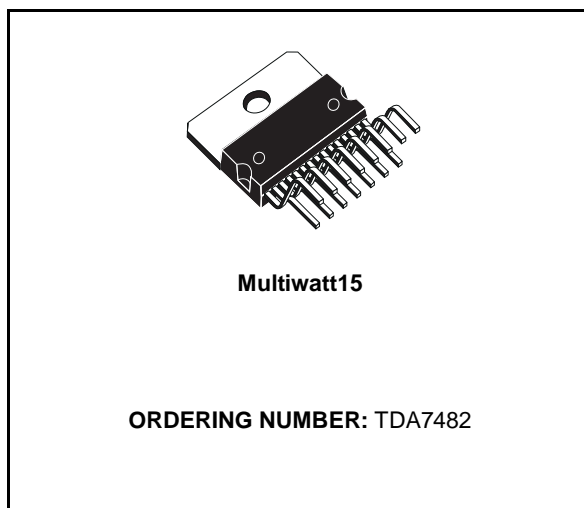


25W MONO CLASS-D AMPLIFIER

PRODUCT PREVIEW

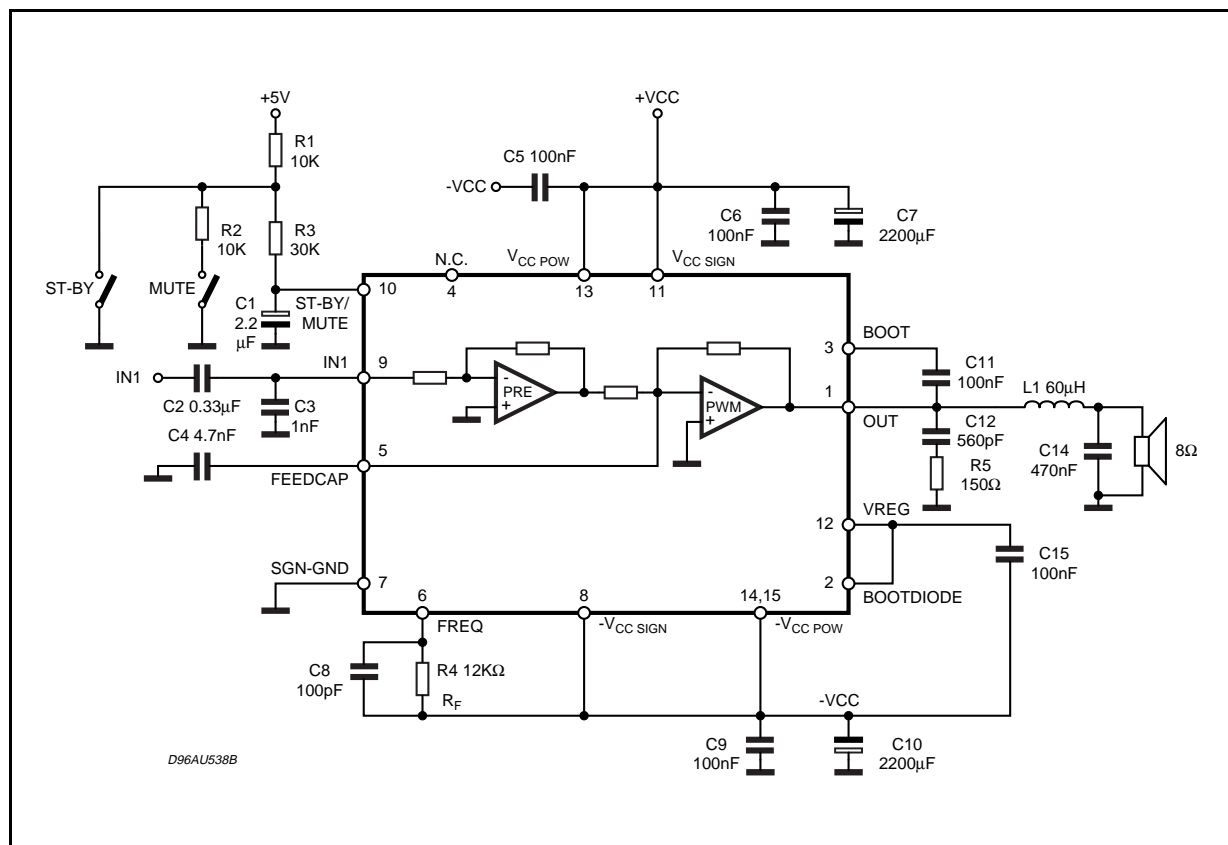
- 25W OUTPUT POWER:
R_L = 8Ω/4Ω; THD = 10%
- HIGH EFFICIENCY
- WIDE SUPPLY VOLTAGE RANGE (UP TO ±25V)
- SPLIT SUPPLY
- OVERVOLTAGE PROTECTION
- ST-BY AND MUTE FEATURES
- SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION



DESCRIPTION

The TDA7482 is an audio class-D amplifier assembled in Multiwatt15 package specially designed for high efficiency applications mainly for TV and Home Stereo sets.

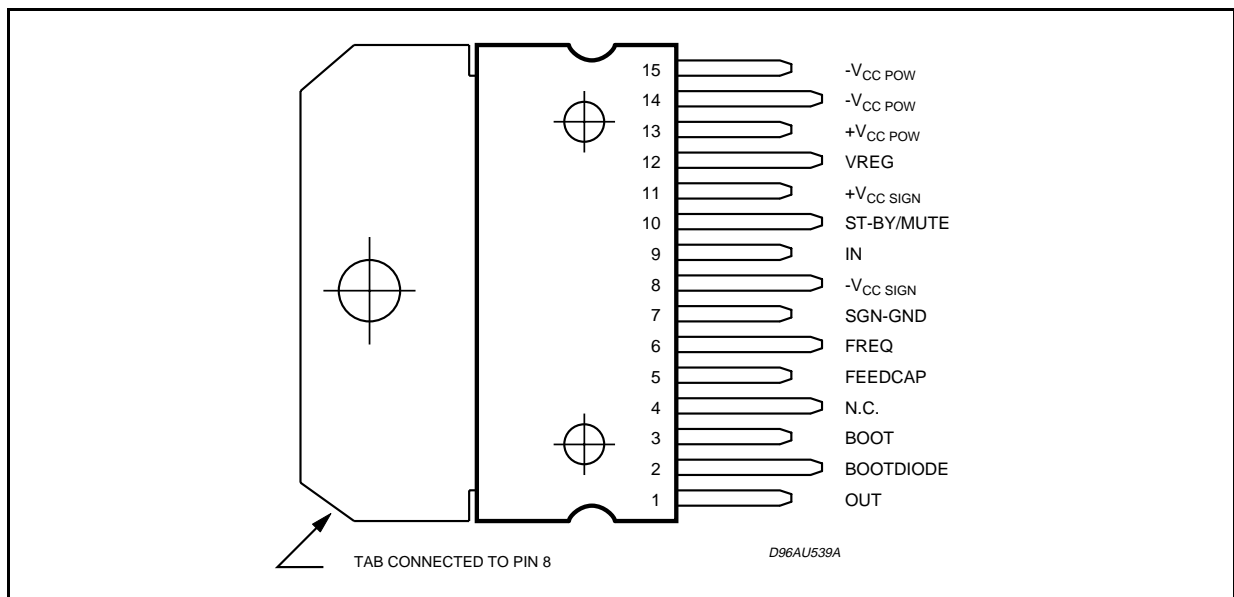
Figure 1: Test and Application circuit.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	± 25	V
P_{tot}	Power Dissipation $T_{case} = 70^{\circ}C$	35	W
T_{stg}, T_j	Storage and Junction Temperature	-40 to 150	$^{\circ}C$
V_{RFmax}	Maximum Voltage Across RF	8	V
T_{op}	Operating Temperature Range	0 to 70	$^{\circ}C$

PIN CONNECTION (Top view)



THERMAL DATA

Symbol	Parameter	Typ.	Max.	Unit
$R_{th\ j-case}$	Thermal Resistance Junction-case	1.8	2.5	$^{\circ}C/W$

PIN FUNCTIONS

N.	Name	Function
1	OUT	PWM OUTPUT
2	BOOTDIODE	BOOTSTRAP DIODE ANODE
3	BOOT	BOOTSTRAP
4	NC	NOT CONNECTED
5	FEEDCAP	FEEDBACK INTEGRATING CAPACITOR
6	FREQ	SETTING FREQUENCY RESISTOR
7	SGN-GND	SIGNAL GROUND
8	$-V_{CC\ SIGN}$	SIGNAL NEGATIVE SUPPLY
9	IN	INPUT
10	ST-BY/MUTE	CONTROL STATE PIN
11	$+V_{CC\ SIGN}$	POSITIVE SIGNAL SUPPLY
12	VREG	INTERNAL VOLTAGE REGULATOR
13	$+V_{CC\ POW}$	POSITIVE POWER SUPPLY
14	$-V_{CC\ POW}$	NEGATIVE POWER SUPPLY
15	$-V_{CC\ POW}$	NEGATIVE POWER SUPPLY

ELECTRICAL CHARACTERISTICS (Refer to the test circuit, $V_{CC} = \pm 21V$; $R_L = 8\Omega$; $R_S = 50\Omega$; $R_{f1} = 12K\Omega$; Demod.. filter $L = 60\mu H$, $C = 470nF$; $f = 1KHz$; $T_{amb} = 25^\circ C$ unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_S	Supply Range		± 10		± 25	V
I_q	Total Quiescent Current	$R_L = \infty$		40		mA
V_{OS}	Output Offset Voltage		-50		+50	mV
P_O	Output Power	THD = 10% THD = 1%		25 18		W W
P_O	Output Power	$R_L = 4\Omega$; $V_{CC} = \pm 16V$; THD = 10% THD = 1% (*)		25 18		W W
P_D	Maximum Dissipated Power	$V_{CC} = \pm 21V$; $R_L = 8\Omega$; $P_O = 25W$ THD 10%		3.8		W
η	Efficiency $\equiv \frac{P_O}{P_O + P_D} \equiv \frac{P_O}{P_I}$ (**)	$V_{CC} = \pm 21V$; $R_L = 8\Omega$; $P_O = 18W$ THD 10%		87		%
η_{max}	Top Efficiency maximum	$V_{CC} = \pm 25V$; $R_L = 8\Omega$; $P_O = 43W$ THD 20%		88.5		%
THD	Total Harmonic Distortion	$R_L = 8\Omega$; $P_O = 1W$		0.1		%
I_{max}	Overcurrent Protection Threshold	$R_L = 0$	3.5	5		A
T_j	Thermal Shut-down Junction Temperature			150		$^\circ C$
G_V	Closed Loop Gain			30		dB
e_N	Total Input Noise	A Curve $f = 20Hz$ to $22KHz$		7 12		μV μV
$V_{CCTOTMAX}$	Maximum Total V_{CC} Protection		50			V
R_i	Input Resistance			30		$k\Omega$
SVR	Supply Voltage Rejection	$f = 100Hz$; $V_r = 0.5$		60		dB
T_r, T_f	Rising and Falling Time			50		ns
R_{DSON}	Power Transistor on Resistance			0.4		Ω
F_{SW}	Switching Frequency Range		100		200	KHz
B_F	Zero Signal Frequency Constant (***)			1.4×10^9		Hz Ω
R_F	Frequency Controller Resistor Range (****)		7	12	14	$K\Omega$
MUTE & STAND-BY FUNCTIONS						
V_{ST-BY}	Stand-by range		0		0.7	V
V_{MUTE}	Mute Range		1.7		2.5	V
V_{PLAY}	Play Range		4		5	V
A_{MUTE}	Mute Attenuation			60		dB
I_{qST-BY}	Quiescent Current @ Stand-by			3		mA

*: The output LC filter must be changed to: $L = 30\mu H$; $C = 1\mu F$

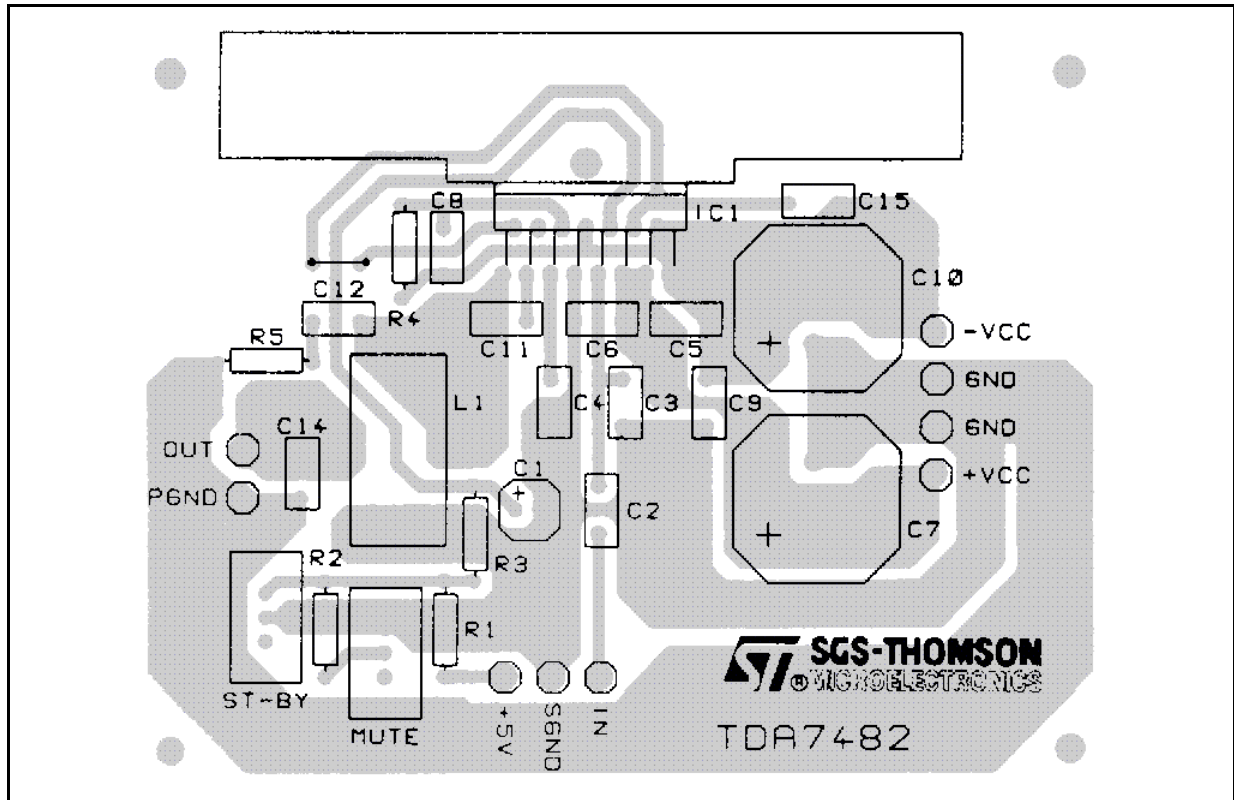
** P_O = measured across the load using the following inductor:
COIL 58120 MPPA2 (magnetics) TURNS: 28 \varnothing 1mm
COIL77120 KOOL M μ (magnetics) TURNS: 28 \varnothing 1mm

***: The zero-signal switching frequency can be obtained using the following expression: $F_{SW} = B_F/R_F$

****: The maximum value of R_F is related to the maximum possible value for the voltage drop on R_F itself

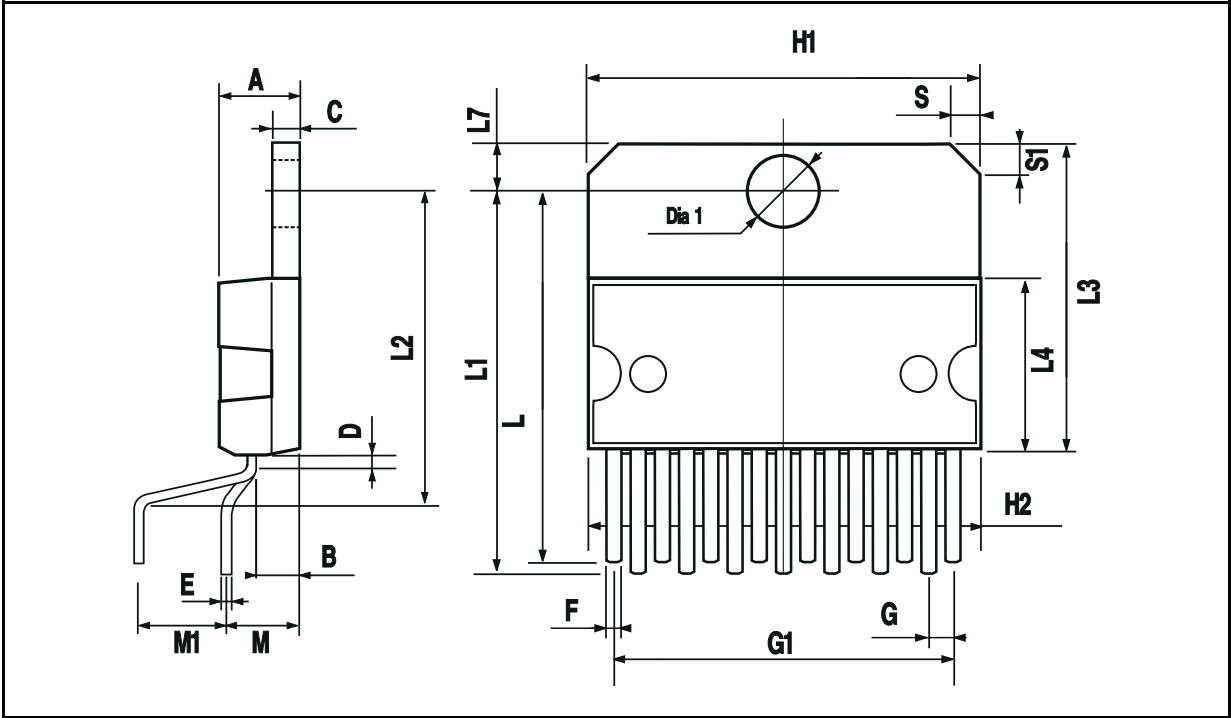
TDA7482

Figure 2: P.C. Board and Component Layout of the Circuit of Figure 1 (1.25:1 scale)



MULTIWATT15 PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.02	1.27	1.52	0.040	0.050	0.060
G1	17.53	17.78	18.03	0.690	0.700	0.710
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.870	0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.63	5.08	5.53	0.182	0.200	0.218
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152



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